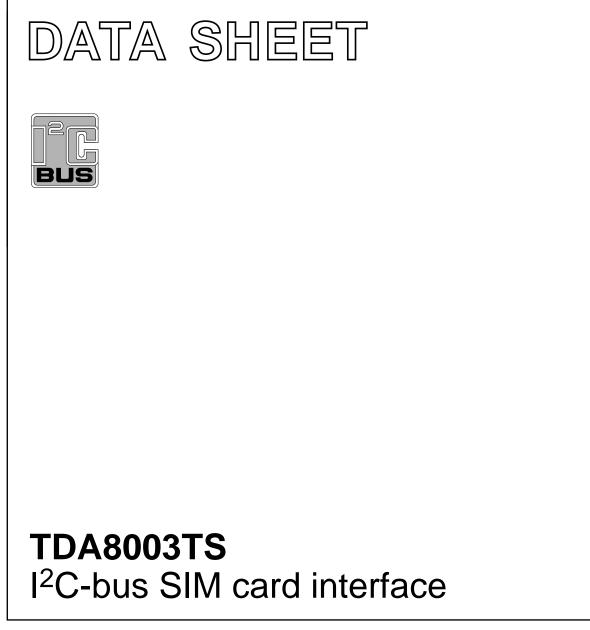
INTEGRATED CIRCUITS



Product specification Supersedes data of 2000 Feb 29 File under Integrated Circuits, IC02 2000 Apr 20



Semiconductors

Philips

TDA8003TS

I²C-bus SIM card interface

FEATURES

- Subscriber Identification Module (SIM) card interface in accordance with GSM11.11, GSM11.12 (Global System for Mobile communication) and ISO 7816 requirements
- + V_{CC} regulation (3 or 5 V $\pm 8\%$) with controlled rise and fall times
- · Card take-off protection
- One protected and buffered pseudo-bidirectional I/O line (I/O referenced to V_{CC} and SIMI/O referenced to V_{DDI})
- Clock generation (up to 10 MHz) with synchronous start and frequency doubling
- Clock stop LOW, clock stop HIGH or 1.25 MHz (from internal oscillator) for cards Power-down mode
- Automatic activation and deactivation sequences of an independent sequencer
- Automatic processing of pin RST with count of the CLK cycles for start of the Answer To Reset (ATR)
- Warm reset command
- Supply voltage supervisor for Power-on reset, spike killing and emergency deactivation in case of supply drop-out
- DC-to-DC converter (doubler, tripler or follower) allowing operation in a 3 or 5 V environment $(2.5 \le V_{DD} \le 6 \text{ V})$
- Enhanced Electrostatic Discharge (ESD) protections on card side (6 kV minimum)
- Power-down mode with several active features and current reduction
- Off mode with 2 µA current
- Control from a microcontroller via a 400 kHz slave l²C-bus (4 possible addresses: 48H, 4AH, 4CH and 4EH)
- Four parallel devices possible due to 2 sub-address wires
- Interface signals supplied by an independent voltage (1.5 \leq V_{DDI} \leq 6 V).



APPLICATIONS

- GSM mobile phones
- · SAM interfaces in banking terminals
- Portable card readers, etc.

GENERAL DESCRIPTION

The TDA8003TS is a low cost one chip SIM interface, in accordance with GSM11.11, GSM11.12 and EMV96 (Europay, Mastercard, Visa) with card current limitation. Controlled by I²C-bus, it is optimized in terms of board space, external components count and connection count (see Chapter "Application information").

The integrated DC-to-DC converter ensures full cross-compatibility between 3 or 5 V cards and 3 or 5 V environments. The very low-power consumption in Power-down mode and Off mode saves battery power.

TYPE		PACKAGE	
NUMBER	NAME	AME DESCRIPTION	
TDA8003TS/C1	SSOP24	plastic shrink small outline package; 24 leads; body width 5.3 mm	SOT340-1
TDA8003TS/C2	SSOP24	plastic shrink small outline package; 24 leads; body width 5.3 mm	SOT340-1

TDA8003TS

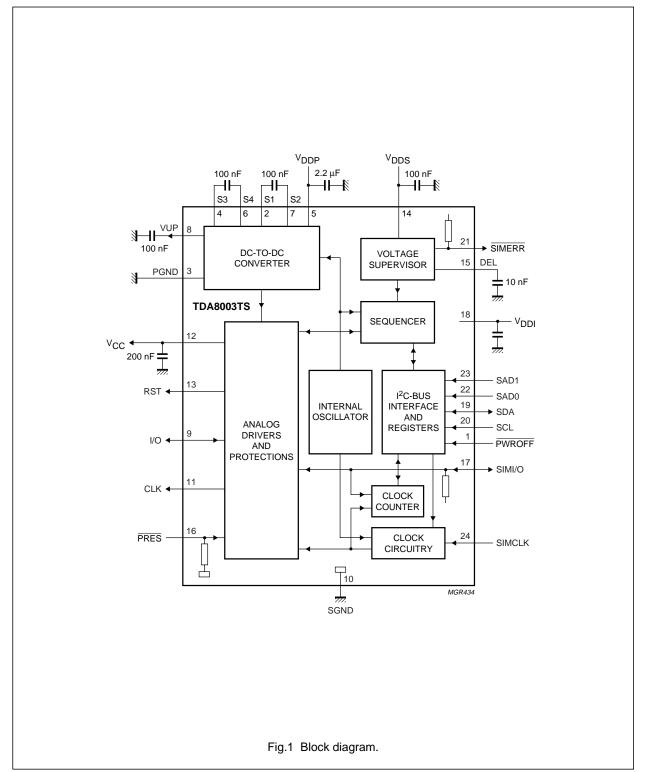
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{DD}	supply voltage on pins V_{DDS} and V_{DDP}		2.5	-	6	V
I _{DD}	supply current on pins V _{DDS}	Off mode; V _{DD} = 3 V	-	-	2	μA
	and V _{DDP}	Power-down mode; $V_{DD} = 3 V$; $V_{CC} = 5 V$; $I_{CC} = 100 \mu$ A; SIMCLK connected to PGND or V_{DDI} ; CLK is stopped	-	-	500	μΑ
		active mode; V_{DD} = 3 V; V_{CC} = 3 V; I_{CC} = 6 mA; f_{CLK} = 3.25 MHz	-	-	18	mA
		active mode; $V_{DD} = 3 \text{ V}$; $V_{CC} = 5 \text{ V}$; $I_{CC} = 10 \text{ mA}$; $f_{CLK} = 3.25 \text{ MHz}$	-	-	50	mA
		active mode; $V_{DD} = 5 V$; $V_{CC} = 3 V$; $I_{CC} = 6 mA$; $f_{CLK} = 3.25 MHz$	-	-	10	mA
		active mode; $V_{DD} = 5 \text{ V}$; $V_{CC} = 5 \text{ V}$; $I_{CC} = 10 \text{ mA}$; $f_{CLK} = 3.25 \text{ MHz}$	-	-	30	mA
V _{DDI}	interface signal supply voltage		1.5	-	6	V
V _{CC}	card supply voltage	5 V card; active mode; 0 < I _{CC} < 15 mA; 40 nAs dynamic load on 200 nF capacitor	4.6	5	5.4	V
		3 V card; active mode; 0 < I _{CC} < 10 mA; 24 nAs dynamic load on 200 nF capacitor	2.75	3	3.25	V
		5 V card; bit PDOWN = 1; I_{CC} < 5 mA	4.6	-	5.4	V
		3 V card; bit PDOWN = 1; $I_{CC} < 5 \text{ mA}$	2.75	-	3.25	V
SR	slew rate on V_{CC} (rise and fall)	C _{L(max)} = 200 nF	0.05	-	0.25	V/µs
t _{de}	deactivation time		-	-	120	μs
t _{act}	activation time		-	-	150	μs
f _{i(SIMCLK)}	clock input frequency		0	-	20	MHz
T _{amb}	operating ambient temperature		-40	-	+85	°C

TDA8003TS

I²C-bus SIM card interface

BLOCK DIAGRAM



TDA8003TS

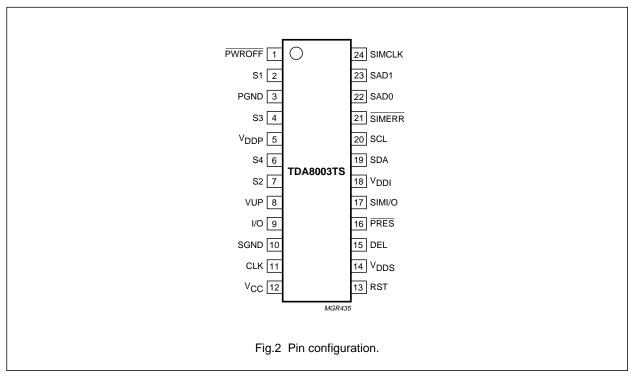
PINNING

	1
PIN	DESCRIPTION
1	control input for entering the Off mode (active LOW)
2	capacitor connection for the DC-to-DC converter (between S1 and S2)
3	power ground
4	capacitor connection for the DC-to-DC converter (between S3 and S4)
5	power supply voltage
6	capacitor connection for the DC-to-DC converter (between S3 and S4)
7	capacitor connection for the DC-to-DC converter (between S1 and S2)
8	DC-to-DC converter output (must be decoupled with 100 nF to ground)
9	input/output to and from the card reader (C7I); see Fig.7
10	signal ground
11	clock output to the card reader (C3I)
12	supply voltage to the card reader (C1I)
13	reset output to the card reader (C2I)
14	signal supply voltage
15	external capacitor connection for the delay on voltage supervisor
16	card presence indication input (active LOW); note 1
17	input/output to and from the microcontroller (internal 20 k Ω pull-up resistor connected to V _{DDI})
18	supply voltage for the interface signals with the system
19	I ² C-bus serial data input/output
20	I ² C-bus serial clock input
21	interrupt output (active LOW; internal 100 k Ω pull-up resistor connected to V _{DDI})
22	I ² C-bus slave address selection input
23	I ² C-bus slave address selection input
24	external clock input
	1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 20 21 22 23

Note

 Card presence input with negative current source. To be used with the card reader switch connected to V_{DDS} or V_{DDP}. The switch is normally closed when the card is not present. If the switch connection is open-circuit or pin 16 is not connected, then the interface will always detect a present card (see Fig.7).

TDA8003TS



FUNCTIONAL DESCRIPTION

Figure 1 shows the block diagram of the TDA8003TS. The functional blocks are described in the following sections. It is assumed that the reader of this specification is aware of GSM11.11 and ISO 7816 terminology.

I²C-bus control

The I²C-bus interface is used:

- To configure the clock to the card in active mode $(1^{\prime}_{2}f_{SIMCLK}$ and $1^{\prime}_{4}f_{SIMCLK})$
- To configure the clock to the card in power reduction mode (stop LOW, stop HIGH or ±1.25 MHz derived from the internal oscillator)
- To select operation with a 3 or 5 V card
- To start or stop sessions (cold reset)
- To initiate a warm reset
- To enter or leave the Power-down mode
- To request the status (card present or not, hardware problem occurred, unresponsive card after activation, supply drop-out detected by the voltage supervisor, card powered or not)
- To configure SIMI/O and I/O in high-impedance (for use of several TDA8003TS in parallel).

The structure of the I²C-bus data frames is as follows:

- Commands to the TDA8003TS:
 - START/ADDRESS/WRITE
 - COMMAND BYTE
 - STOP.

The fixed address is 01001XY. X and Y are defined by the logic levels on pins SAD1 and SAD0 as shown in Table 1 (connect to ground for logic 0; connect to V_{DDI} for logic 1). The command bits are described in Table 2. The commands are executed on the rising edge of the 9th SCL pulse.

• Status from the TDA8003TS (see Table 4). The fixed address is 01001XY. X and Y are defined by the logic levels on pins SAD1 and SAD0 as shown in Table 1.

Table 1 Address selections

ADDRESS	SAD1	SAD0
48H	0	0
4AH	0	1
4CH	1	0
4EH	1	1

TDA8003TS

SYMBOL	BIT	DESCRIPTION
START/STOP	0	Logic 1 initiates an activation sequence and a cold reset procedure. Logic 0 initiates a deactivation sequence.
WARM	1	Logic 1 initiates a warm reset procedure. TDA8003TS/C1: warm reset performed only when the 2 times 45000 CLK pulses have expired without answer from the card.
		TDA8003TS/C2: warm reset performed whatever the card has answered or not at the cold reset procedure but the count is 2 times 44745 CLK pulses.
3 V/5 VN	2	Logic 1 sets the card supply voltage V _{CC} to 3 V. Logic 0 sets V _{CC} to 5 V.
PDOWN	3	Logic 1 applies on CLK the frequency defined by bits CLKPD1 and CLKPD2, and enters a reduced consumption mode. Logic 0 sets the circuit back to normal mode.
CLKPD1	4	Bits 4 and 5 determine the clock to the card at power-down as shown in Table 3.
CLKPD2	5	
DT/DFN	6	Logic 1 sets f_{CLK} to $\frac{1}{2}f_{SIMCLK}$ (in active mode). Logic 0 sets f_{CLK} to $\frac{1}{4}f_{SIMCLK}$.
I/OEN	7	Logic 1 will transfer I/O to SIMI/O. Logic 0 sets I/O and SIMI/O to high-impedance.

Table 2 Description of the command bits; (all bits are cleared at reset)

Table 3 Clock to the card at power-down

BIT 4	BIT 5	FUNCTION
0	0	clock stop LOW
0	1	clock stop HIGH
1	0	clock is ½fosc
1	1	no change

Table 4Description of the status bits; note 1

SYMBOL	BIT	DESCRIPTION
PRES	0	Logic 1 when the card is present. Logic 0 when the card is not present.
PRESL	1	Logic 1 when the card has been extracted or inserted. Logic 0 when the status is read-out.
_	2	Bit 2 is not used and is fixed to logic 0.
SUPL	3	Logic 1 when the voltage supervisor has signalled a fault. Logic 0 when the status is read-out.
PROT	4	Logic 1 when an overload has occurred during a session. Logic 0 when the status is read-out.
MUTE	5	TDA8003TS/C1: Logic 1 when a card has not answered after 2 times 45000 CLK pulses. Logic 0 when the status is read-out.
		TDA8003TS/C2: Same as for C1, but the count is 2 times 44745 CLK pulses.
EARLY	6	Logic 1 when a card has answered between 200 and 352 CLK cycles. Logic 0 when the status is read-out.
ACTIVE	7	Logic 1 when the card is power-on. Logic 0 when the card is power-off.

Note

In case of card extraction, supply drop-out or overload detection within a session, the card will be automatically deactivated, SIMERR pulled LOW, bit START = 0 and the corresponding status bit = 1. The status bit will be logic 0 and SIMERR will be released when the microcontroller reads out the status register, on the 7th SCL pulse. After a supply drop-out, SIMERR will be released at the end of the alarm pulse and bit SUPL = 1.

TDA8003TS

Power supply

The circuit operates within a supply voltage range of 2.5 to 6 V. The supply pins are V_{DDS} and SGND. Pins V_{DDP} and PGND only supply the DC-to-DC converter for the analog drivers to the card and must be decoupled externally because of the large current spikes that the card and the DC-to-DC converter can create. An integrated spike killer ensures the card contacts to remain inactive during power-up or power-down. An internal voltage reference is generated for the DC-to-DC converter, the voltage supervisor and the V_{CC} generator.

All interface signals with the microcontroller (\overline{PWROFF} , SIMCLK, SAD1, SAD0, \overline{SIMERR} , SCL, SDA and SIMI/O) are referenced to a separate supply pin V_{DDI}, which may be different from V_{DD} ($1.5 \le V_{DDI} \le 6$ V).

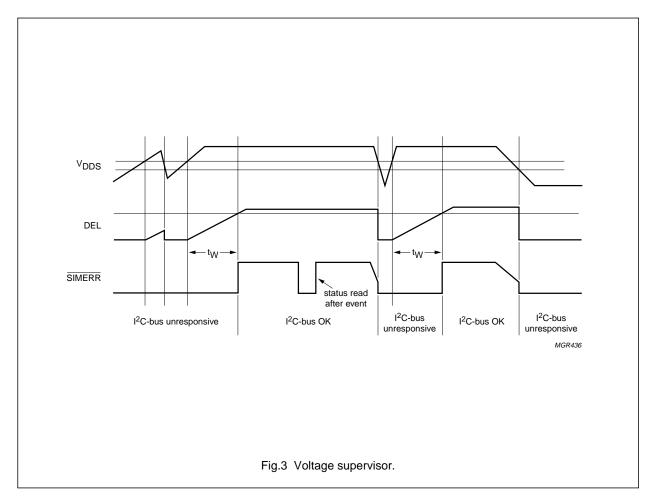
The pull-up resistors on bus lines SDA and SCL may be referenced to a voltage higher than V_{DDI} . This allows the use of peripherals which do not operate at V_{DDI} .

The voltage supervisor (see Fig.3) senses V_{DDS} . It generates an alarm pulse, whose length t_W is defined by an external capacitor connected to pin DEL, when V_{DD} is too low to ensure proper operation (1 ms per 1 nF typical).

During this alarm pulse, SIMERR is LOW and the I²C-bus is unresponsive. SIMERR goes back to HIGH, and the I²C-bus becomes operational at the end of this alarm pulse. Bit SUPL is set as long as the status has not been read.

It is also used to either block any spurious signals on card contacts during microcontroller reset, or to force an automatic deactivation of the contacts in the event of supply drop-out.

Outside a card session, SIMERR is LOW as long as the voltage supervisor is active. If a supply drop-out occurs during a session, SIMERR falls to LOW, bit START is cleared and an automatic deactivation is initiated.



TDA8003TS

DC-to-DC converter

The whole circuit is powered by V_{DDS} , except for the V_{CC} generator, the other card contact buffers and the interface signals.

The DC-to-DC converter acts as a doubler or a tripler, depending on the supply voltage V_{DD} and the card supply voltage V_{CC} . There are basically four possible situations:

- V_{DD} = 3 V and V_{CC} = 3 V. The DC-to-DC converter acts as a doubler with a regulation of V_{VUP} at approximately 4.5 V
- V_{DD} = 3 V and V_{CC} = 5 V. The DC-to-DC converter acts as a tripler with a regulation of V_{VUP} at approximately 6.5 V
- V_{DD} = 5 V and V_{CC} = 3 V. The DC-to-DC converter is disabled and V_{DD} is applied to pin VUP
- V_{DD} = 5 V and V_{CC} = 5 V. The DC-to-DC converter acts as a doubler with a regulation of V_{VUP} at approximately 6.5 V.

The supply voltage is recognized by the TDA8003TS at approximately 3.75 V for the C1 and 3.3 V for the C2.

When a card session is requested by the microcontroller, the sequencer will first start the DC-to-DC converter, which is a switched capacitor type, clocked by an internal oscillator at a frequency f_{osc} of approximately 2.5 MHz. The output voltage V_{VUP} is regulated at approximately 4.5 or 6.5 V and subsequently fed to the V_{CC} generator. V_{CC} and PGND are used as a reference for all other card contacts.

Power-down mode

The Power-down mode is used for current consumption reduction when the card is in Sleep mode.

To enter Power-down mode, the microcontroller must first select CLK in this mode (stop LOW, stop HIGH or 1.25 MHz from the internal oscillator) with bits CLKPD1 and CLKPD2. Subsequently, the microcontroller sends the command PDOWN, CLK is switched to the value predefined by bits CLKPD1 and CLKPD2, and SIMCLK may be stopped (HIGH or LOW).

If the selected CLK is stopped, the biasing currents in the buffers to the card will be reduced. The voltage supervisor and all control functions also remain active. The maximum current taken by the card in this mode when CLK is stopped is assumed to be less than 5 mA.

Before leaving the Power-down mode, the clock signal must first be applied to SIMCLK, and then bit PDOWN must be set to logic 0.

Off mode

The Off mode is entered when the \overline{PWROFF} signal is LOW. In this mode, no function is valid. This mode avoids switching off the power supply of the device, and gives a current consumption less than 2 μA . Before entering the Off mode, the card must be deactivated.

The Off mode is resumed when the PWROFF signal returns to HIGH. This re-initializes the voltage supervisor, and has the same effect as a reset of the device. As long as the device is not ready to operate, the SIMERR signal will remain LOW.

Sequencer and clock counter

The sequencer handles the ensuring activation and deactivation sequences in accordance with GSM11.11 and ISO 7816, even in case of emergency (card take-off, short circuit and supply drop-out). The sequencer is clocked with the internal oscillator frequency f_{osc} .

The activation is initiated with the START command (only if the card is present, and if the voltage supervisor does not detect a fault on the supply). During activation, V_{CC} goes HIGH and subsequently I/O is enabled and CLK is started with RST = LOW. The clock counter counts the CLK pulses till a start bit is detected on I/O.

After 45000 CLK pulses for the C1 (44745 for the C2), if no start bit on I/O has been detected, the sequencer toggles RST to HIGH, and counts again 45000 CLK pulses (44745 for the C2). If, again, no start bit has been detected, SIMERR will be pulled LOW and the information of bit MUTE is set in the status register.

If a start bit has been detected during the two 45000 CLK pulse slots (44745 for the C2), the clock counter is stopped, RST is kept at the same level and the session can go on between the card and the system.

The clock counter does not take care of any start bit during the 200 first CLK pulses of both slots; if a start bit is detected between 200 and 352 CLK pulses of both slots, then SIMERR will be pulled LOW and the information of bit EARLY is set in the status register.

The deactivation is initiated either by the microcontroller (STOP command), or automatically by the TDA8003TS in case of card take-off, short circuit or supply voltage drop-out detected by the voltage supervisor. During deactivation, RST will go LOW, CLK is stopped, I/O is disabled and V_{CC} goes LOW.

Product specification

TDA8003TS

Clock circuit

The clock to the card is either derived from pin SIMCLK (2 to 20 MHz) or from the internal oscillator.

During a card session, f_{CLK} may be chosen to be $\frac{1}{2}f_{SIMCLK}$ or $\frac{1}{4}f_{SIMCLK}$ depending on bit DT/DFN.

For the card Sleep mode, CLK may be chosen stop LOW, stop HIGH or $^{1}\!/_{2}f_{osc}$ (1.25 MHz) with bits CLKPD1 and CLKPD2. This predefined value will be applied to CLK when bit PDOWN is set to logic 1.

The first CLK pulse has the correct width, and all frequency changes are synchronous, ensuring that no pulse is smaller than 45% of the shortest period.

The duty cycle is within 45 and 55% in stable state, the rise and fall times are less than 8% of the period and precaution has been taken so that there is no overshoot or undershoot.

Activation sequence

Figure 4 shows the activation sequence. When the card is inactive, V_{CC} , CLK, RST and I/O are LOW, with low-impedance with respect to ground. The DC-to-DC converter is stopped. SIMI/O is pulled HIGH at V_{DDI} via the 20 k Ω pull-up resistor. When all conditions are met (supply voltage, card present, no hardware problems), the microcontroller may initiate an activation sequence by setting bit START to logic 1 (t₀) via the I²C-bus:

- 1. The DC-to-DC converter is started (t₁).
- V_{CC} starts rising from 0 to 3 or to 5 V according to 3 V/5 VN control bit with a controlled rise time of 0.17 V/μs typically (t₂).
- 3. I/O buffer is enabled in reception mode (t_3) .
- 4. CLK is sent to the card reader with RST = LOW, and the count of 45000 (44745 for C2) CLK pulses is started ($t_4 = t_{act}$).
- 5. If a start bit is detected on I/O, the clock counter is stopped with RST = LOW. If not, RST = HIGH, and a new count of 45000 (44745 for C2) CLK pulses is started (t_5).

If a start bit is detected on I/O and the clock counter is stopped with RST = HIGH, the card session may continue. If not, bit MUTE is set in the status register and SIMERR is pulled LOW. The microcontroller may initiate a deactivation sequence by setting bit START to logic 0.

If a start bit is detected during the 200 first CLK pulses of each count slot, then it will not be taken into account. If a start bit is detected during 200 and 352 CLK pulses of each slot, then bit EARLY is set in the status register and SIMERR is pulled LOW. The microcontroller may initiate a deactivation sequence by setting bit START to logic 0.

The sequencer is clocked by $\frac{1}{64}f_{osc}$ which leads to a time interval T of 25 μ s typically. Thus $t_1 = 0$ to $\frac{1}{64}T$; $t_2 = t_1 + \frac{3}{2}T$; $t_3 = t_1 + \frac{7}{2}T$; $t_4 = t_1 + 4T$ and t_5 depends on the SIMCLK frequency.

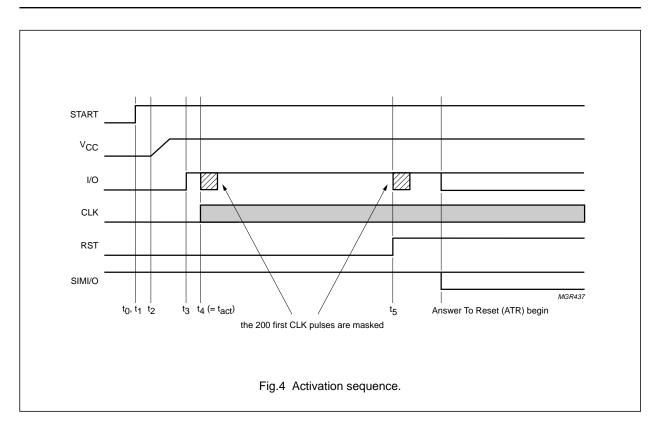
Deactivation sequence

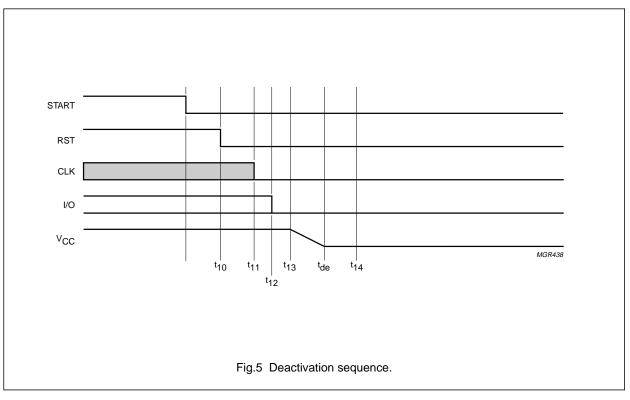
Figure 5 shows the deactivation sequence. When the session is completed, the microcontroller sets bit START to logic 0. The circuit will execute an automatic deactivation sequence:

- 1. Card reset, RST falls to LOW (t₁₀).
- 2. CLK is stopped (t₁₁).
- 3. I/O falls to LOW (t_{12}) .
- 4. V_{CC} falls to 0 V with typically 0.17 V/ μ s slew rate (t₁₃). The deactivation is completed when V_{CC} reaches 0.4 V (t_{de}).
- 5. The DC-to-DC converter is stopped and CLK, RST, V_{CC} and I/O become low-impedance with respect to PGND (t₁₄).

Where $t_{10} < \frac{1}{64}$ T; $t_{11} = t_{10} + \frac{1}{2}$ T; $t_{12} = t_{10} +$ T; $t_{13} = t_{12} + 5 \ \mu s$ and $t_{14} = t_{10} + 4$ T.

TDA8003TS





TDA8003TS

Protections

The following main hardware fault conditions are monitored by the circuit:

- Short circuits between V_{CC} and other contacts
- Card take-off during transaction
- Supply drop-out.

When one of these problems is detected during a card session, the security logic block pulls SIMERR to LOW, to warn the microcontroller and initiates an automatic deactivation of the contacts (see Fig.6).

I/O circuit

The Idle state is realized by both I/O and SIMI/O being pulled HIGH (via a 10 k Ω pull-up resistor from I/O to V_{CC} and via a 20 k Ω pull-up resistor from SIMI/O to V_{DDI}).

I/O is referenced to V_{CC} and SIMI/O to V_{DDI}, thus allowing operation with V_{CC} \neq V_{DD} \neq V_{DDI}.

When configuration bit I/OEN is logic 0, then I/O and SIMI/O are independent, which allows parallelization of several TDA8003TS with only one I/O line on the microcontroller side (up to 4 different I²C-bus addresses).

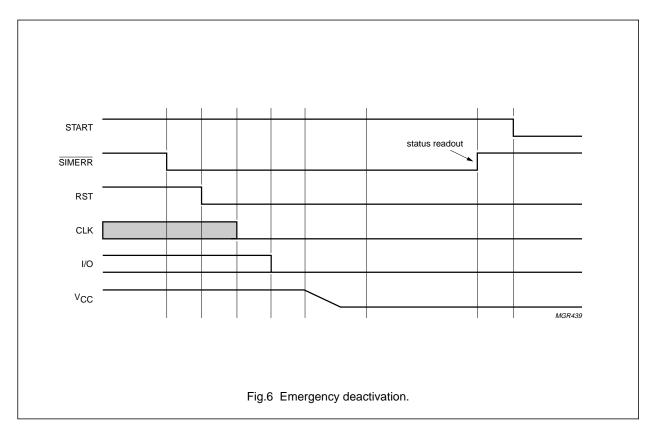
When bit I/OEN is logic 1, then the data transmission between I/O and SIMI/O is enabled.

The first side on which a falling edge occurs becomes the master. An anti-latch circuit disables the detection of falling edges on the other side, which becomes a slave.

After a delay time t_d (<500 ns) on the falling edge, the N transistor on the slave side is turned on, thus transmitting the logic 0 present on the master side.

When the master goes back to logic 1, the P transistor on the slave side is turned on during t_d , and then both sides return to their Idle states.

The maximum frequency on these lines is 1 MHz.



TDA8003TS

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DDP}	power supply voltage		-0.5	+6.5	V
V _{DDS}	signal supply voltage		-0.5	+6.5	V
V _{DDI}	interface signal supply voltage		-0.5	+6.5	V
V _{i(n)}	input voltage				
	on pins 1, 17, 21 and 24		-0.5	+6.5	V
	on pins 15, 16, 22 and 23		-0.5	V _{DDS} + 0.5	V
	on pins 19 and 20		-0.5	+6.5	V
	on pins 9, 11 and 13		-0.5	V _{CC} + 0.5	V
	on pin 12		-0.5	+6.5	V
	on pin 8		-0.5	+7.5	V
	on pins 2, 4, 6 and 7		-0.5	V _{VUP} + 0.5	V
l _{i(n)}	DC input current				
	on pins 1, 17, 19, 20, 21, 22, 23 and 24		-5	+5	mA
	on pin 15		-5	+10	mA
I _{i/o(n)}	DC input/output current				
	on pins 2, 4, 6, 7 and 8		-40	+40	mA
	on pin 16		-5	+5	mA
I _{i/o(17)}	transient input/output current on pin 17	duration 1 ms	-40	+40	mA
P _{tot}	continuous total power dissipation	$T_{amb} = -40$ to +85 °C	_	230	mW
Tj	operating junction temperature		-	125	°C
T _{stg}	IC storage temperature		-55	+150	°C
V _{esd(n)}	electrostatic discharge voltage				
	on pins 9, 11, 12, 13 and 16		-6	+6	kV
	on any other pin		-2	+2	kV

HANDLING

Inputs and outputs are protected against electrostatic discharge in normal handling. However, to be totally safe, it is desirable to take normal precautions appropriate to handle Metal Oxide Semiconductor (MOS) devices.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	102	K/W

TDA8003TS

CHARACTERISTICS

 V_{DD} = 3 V; V_{DDI} = 1.5 V; f_{SIMCLK} = 13 MHz; f_{CLK} = 3.25 MHz; T_{amb} = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Supplies						
V _{DD}	supply voltage on pins V_{DDS} and V_{DDP}		2.5	-	6.0	V
I _{DD}	supply current on pins V _{DDS}	Off mode	-	-	2	μA
	and V _{DDP}	inactive mode	-	-	50	μA
		Power-down mode; $V_{CC} = 5 V$; $I_{CC} = 100 \mu A$; SIMCLK connected to SGND or V_{DDI} ; CLK is stopped	-	-	500	μA
		active mode; $V_{CC} = 3 \text{ V}$; $I_{CC} = 6 \text{ mA}$	-	-	18	mA
		active mode; $V_{CC} = 5 V$; $I_{CC} = 10 \text{ mA}$	-	-	50	mA
		active mode; $V_{DD} = 5 V$; $V_{CC} = 3 V$; $I_{CC} = 6 mA$	-	-	10	mA
		active mode; $V_{DD} = 5 V$; $V_{CC} = 5 V$; $I_{CC} = 10 \text{ mA}$	-	-	30	mA
V _{DDI}	interface signal supply voltage		1.5	-	6	V
I _{DDI}	interface signals supply current	SIMCLK connected to PGND or V _{DDI}	-	-	2	μA
		f _{SIMCLK} = 13 MHz; V _{DDI} = 1.5 V	-	-	120	μA
V _{th(VDD)}	threshold voltage on V _{DD}	falling edge	2	-	2.3	V
V _{hys}	hysteresis voltage on $V_{th(VDD)}$		40	-	200	mV
V _{th(DEL)}	threshold voltage on pin DEL		-	1.38	-	V
V _{DEL}	voltage on pin DEL		-	-	V _{DD}	V
I _{ch(DEL)}	charge current on pin DEL		-0.5	-1	-2.5	μA
I _{dch(DEL)}	discharge current on pin DEL	$V_{DEL} = V_{DD}$	0.5	-	-	mA
t _W	alarm pulse width	C _{DEL} = 10 nF	15	-	25	ms
Pin SIMCL	_K					
f _{i(SIMCLK)}	clock input frequency		0	-	20	MHz
t _f	fall time		-	-	1	μs
t _r	rise time		-	-	1	μs
V _{IL}	LOW-level input voltage		0	-	0.3V _{DDI}	V
V _{IH}	HIGH-level input voltage		0.7V _{DDI}	-	V _{DDI} + 0.3	V
IL	leakage current		-	-	±3	μA
DC-to-DC	converter					
¹ / ₂ f _{osc}	oscillator frequency		1	-	1.6	MHz
V _{VUP}	voltage on pin VUP	5 V card	-	6.0	-	V
		3 V card	_	4.5	_	V

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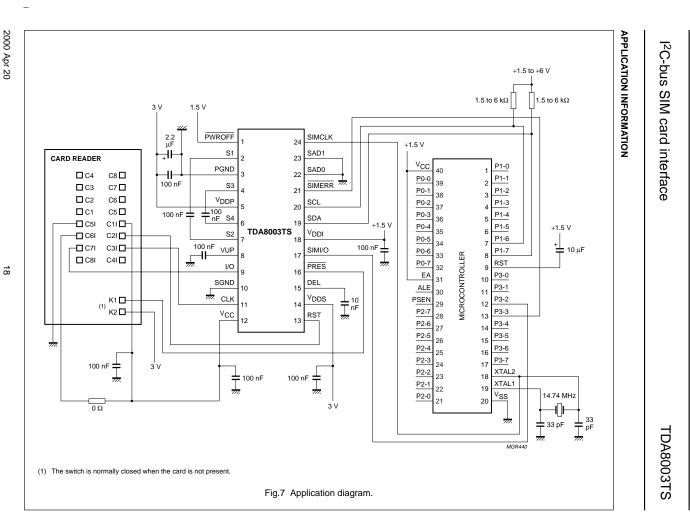
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Pin SDA (open-drain)	-		1		
V _{IL}	LOW-level input voltage		-0.3	_	+0.3V _{DDI}	V
V _{IH}	HIGH-level input voltage		0.7V _{DDI}	_	6	V
I _{LH}	HIGH-level leakage current		-	-	1	μA
IIL	LOW-level input current	depends on the pull-up resistor	-	-	-	μA
V _{OL}	LOW-level output voltage	I _{OL} = 3 mA	-	-	0.3	V
Pin SCL (open-drain)	•	•			
V _{IL}	LOW-level input voltage		-0.3	_	+0.3V _{DDI}	V
V _{IH}	HIGH-level input voltage		0.7V _{DDI}	_	6	V
ILI	input leakage current		-	-	1	μA
Pin SIME	\overline{RR} (100 k Ω pull-up resistor to	V _{DDI})				
V _{OL}	LOW-level output voltage	I _{OL} < 1 mA	_	-	0.3V _{DDI}	V
V _{OH}	HIGH-level output voltage	I _{OH} < -1 μA	0.7V _{DDI}	-	-	V
Pins SAD	0, SAD1 and PWROFF	-		1		
V _{IL}	LOW-level input voltage		0	-	0.3V _{DDI}	V
V _{IH}	HIGH-level input voltage		0.7V _{DDI}	_	V _{DDI} + 0.3	V
ILI	input leakage current		-	-	±1	μA
Pin RST			•	1		
Vo	output voltage	inactive mode; $I_0 = 1 \text{ mA}$	-0.3	-	+0.4	V
lo	output current	inactive mode; pin RST short circuit to ground	-	-	-1	mA
V _{OL}	LOW-level output voltage	I _{OL} = 200 μA	-0.2	-	+0.3	V
V _{OH}	HIGH-level output voltage	I _{OH} < -200 μA	V _{CC} – 0.5	-	V _{CC} + 0.2	V
t _f	fall time	C _L = 30 pF	-	-	0.5	μs
t _r	rise time	C _L = 30 pF	-	-	0.5	μs
Pin CLK						
Vo	output voltage	inactive mode; $I_0 = 1 \text{ mA}$	-0.3	-	+0.4	V
IO	output current	inactive mode; pin CLK short circuit to ground	-	-	-1	mA
V _{OL}	LOW-level output voltage	I _{OL} = 200 μA	-0.2	-	+0.3	V
V _{OH}	HIGH-level output voltage	I _{OH} = -200 μA	V _{CC} – 0.5	-	V _{CC} + 0.2	V
t _f	fall time	C _L = 30 pF	-	-	8	ns
t _r	rise time	C _L = 30 pF	-	-	8	ns
f _{clk}	clock frequency	1 MHz power-down configuration	1	-	1.5	MHz
		regular activity	0	-	10	MHz
δ	duty factor	C _L = 30 pF	45	-	55	%

TDA8003TS

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Pin V _{CC}		•		•		•
Vo	output voltage	inactive mode; I _O = 1 mA	-	-	0.4	V
		active mode; 5 V card; no load	4.85	5.10	5.40	V
		active mode; 3 V card; no load	2.8	3.05	3.22	V
		active mode; with 200 nF capacitor; including static load (up to 20 mA) and dynamic current pulses; $I_{max} = 200$ mA, $f_{max} = 5$ MHz; duration <400 ns				
		5 V card; 40 nAs pulses	4.60	-	5.40	V
		3 V card; 24 nAs pulses	2.75	-	3.22	V
lo	output current	inactive mode; pin V _{CC} short circuit to ground	-	-	-1	mA
		$V_{CC} = 5 \text{ or } 3 \text{ V}; V_{DD} = 2.5 \text{ V}$	-	-	15	mA
		$V_{CC} = 5 \text{ or } 3 \text{ V}; V_{DD} = 5.5 \text{ V}$	-	-	40	mA
I _{CC}	output current	V _{CC} short circuit to ground	-	-	120	mA
SR	slew rate on V_{CC} (rise and fall)	C _{L(max)} = 300 nF	0.05	0.17	0.25	V/µs
Pin I/O					•	
Vo	output voltage	inactive mode; I _O = 1 mA	-	-	0.4	V
lo	output current	inactive mode; pin I/O short circuit to ground	-	-	-1	mA
V _{OL}	LOW-level output voltage	I _{OL} = 1 mA	-0.2	-	+0.4	V
V _{OH}	HIGH-level output voltage	+25 < I _{OH} < –25 μA	0.8V _{CC}	-	V _{CC} + 0.2	V
V _{IL}	LOW-level input voltage		-0.3	-	+0.8	V
V _{IH}	HIGH-level input voltage		1.5	-	V _{CC} + 0.3	V
I _{LIH}	HIGH-level input leakage current		-	-	10	μA
IIL	LOW-level input current		-	-	-600	μA
t _{t(DI)}	data input transition time	C _L = 30 pF	-	-	1	μs
t _{t(DO)}	data output transition time	C _L = 30 pF	-	-	0.5	μs
t _d	delay time on falling edge		-	-	500	ns
R _{pu(int)}	internal pull-up resistance	C1 version	8	-	13	kΩ
	between pins I/O and $V_{\mbox{\scriptsize CC}}$	C2 version	13	-	18	kΩ
Pin SIMI/C	D					
V _{OL}	LOW-level output voltage	I _{OL} = 1 mA	-0.2	-	+0.3	V
V _{OH}	HIGH-level output voltage	with internal 20 k Ω pull-up resistor to V _{DDI} ; I _O = 10 μ A	V _{DDI} – 0.3	-	V _{DDI} + 0.2	V
V _{IL}	LOW-level input voltage		-0.3	-	+0.3V _{DDI}	V
V _{IH}	HIGH-level input voltage		0.7V _{DDI}	-	V _{DDI} + 0.3	V
I _{LIH}	HIGH-level input leakage current		-	-	10	μA

TDA8003TS

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{IL}	LOW-level input current	with internal 20 k Ω pull-up resistor to V _{DDI} ; V _I = 0 V	-	-	-100	μA
t _{t(DI)}	data input transition time	C _L = 30 pF	-	-	1	μs
t _{t(DO)}	data output transition time	C _L = 30 pF	-	-	0.5	μs
t _d	delay time on falling edge		-	-	500	ns
R _{pu(int)}	internal pull-up resistance between pins SIMI/O and V _{DDI}		16	-	26	kΩ
Pin PRES						-
V _{IL}	LOW-level input voltage		-0.3	-	+0.3V _{DD}	V
V _{IH}	HIGH-level input voltage		0.7V _{DD}	-	V _{DD} + 0.3	V
IIL	LOW-level input current		-	_	5	μA
IIH	HIGH-level input current		-	-	-5	μA
Timing			•	•	•	
t _{act}	activation time		-	-	150	μs
t _{de}	deactivation time		-	-	120	μs



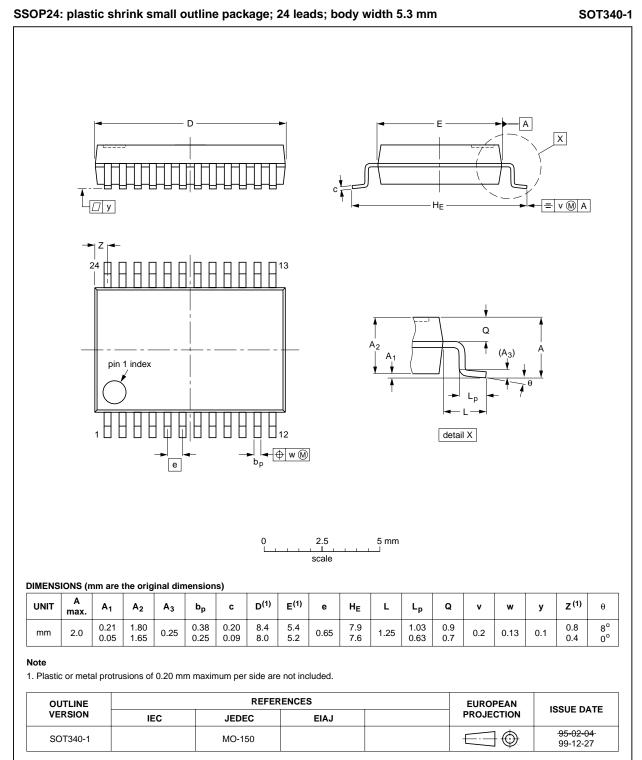
2000 Apr 20

Product specification

Philips Semiconductors

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PACKAGE OUTLINE



TDA8003TS

SOLDERING

Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering is not always suitable for surface mount ICs, or for printed-circuit boards with high population densities. In these situations reflow soldering is often used.

Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, infrared/convection heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferable be kept below 230 °C.

Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is preferred to be parallel to the transport direction of the printed-circuit board;
 - smaller than 1.27 mm, the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

• For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C. A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to $300 \,^{\circ}$ C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 $^\circ$ C.

TDA8003TS

Suitability of surface mount IC packages for wave and reflow soldering methods

PACKAGE	SOLDERING METHOD		
FACKAGE	WAVE	REFLOW ⁽¹⁾	
BGA, LFBGA, SQFP, TFBGA	not suitable	suitable	
HBCC, HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, SMS	not suitable ⁽²⁾	suitable	
PLCC ⁽³⁾ , SO, SOJ	suitable	suitable	
LQFP, QFP, TQFP	not recommended ⁽³⁾⁽⁴⁾	suitable	
SSOP, TSSOP, VSO	not recommended ⁽⁵⁾	suitable	

Notes

- 1. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the "Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods".
- 2. These packages are not suitable for wave soldering as a solder joint between the printed-circuit board and heatsink (at bottom version) can not be achieved, and as solder may stick to the heatsink (on top version).
- 3. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- 4. Wave soldering is only suitable for LQFP, TQFP and QFP packages with a pitch (e) equal to or larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- 5. Wave soldering is only suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

TDA8003TS

DATA SHEET STATUS

DATA SHEET STATUS	PRODUCT STATUS	DEFINITIONS ⁽¹⁾
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

Note

1. Please consult the most recently issued data sheet before initiating or completing a design.

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